Vishay Semiconductors

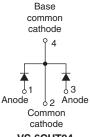
## High Performance Schottky Generation 5.0, 2 x 3 A

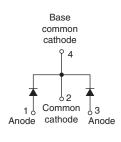




I-PAK (TO-251AA)

D-PAK (TO-252AA)





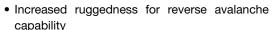
VS-6CUT04

VS-6CWT04FN

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA), I-PAK (TO-251AA)				
I <sub>F(AV)</sub>	2 x 3 A				
$V_{R}$	45 V				
V <sub>F</sub> at I <sub>F</sub>	0.54 V				
I <sub>RM</sub> max.	3 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	14 mJ				

#### **FEATURES**

- 175 °C high performance Schottky diode
- · Very low forward voltage drop
- Extremely low reverse leakage
- Optimized V<sub>F</sub> vs. I<sub>R</sub> trade off for high efficiency



- RBSOA available
- · Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC

#### **APPLICATIONS**

- Specific for PV cells pybass diode
- High efficiency SMPS
- · High frequency switching
- Output rectification
- · Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	OL CHARACTERISTICS VALUES UNITS						
V <sub>RRM</sub>		45	V				
V <sub>F</sub>	3 Apk, T <sub>J</sub> = 125 °C (typical, per leg)	0.46	V				
TJ	Range - 55 to 175 °C						

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-6CUT04 VS-6CWT04FN	UNITS
Maximum DC reverse voltage	$V_{R}$	T <sub>J</sub> = 25 °C	45	V

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average	per leg		50 % duty cycle at T <sub>C</sub> = 166 °C, rectangular waveform		FO 0/ duty avalant T 166 °C vactor gular vacyatores		3	^
forward current	per device	- I <sub>F(AV)</sub>			6	Α		
Maximum peak one cy	/cle	1	5 μs sine or 3 μs rect. pulse Following any rated load condition and with rated		440	А		
non-repetitive surge current per leg		I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	70	^		
Non-repetitive avalance energy per leg	che	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1.3 A, L = 16 mH		14	mJ		
Repetitive avalanche of	current per leg	I <sub>AR</sub>	Limited by frequency of operation and time pulse duration so that $T_J < T_J max$ . $I_{AS}$ at $T_J max$ . as a function of time pulse (see fig. 8)		I <sub>AS</sub> at T <sub>J</sub> max.	А		

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop per leg	V <sub>FM</sub> <sup>(1)</sup>	3 A	T 05 %C	0.535	0.600	V
		6 A	T <sub>J</sub> = 25 °C	0.615	0.680	
		3 A	T <sub>J</sub> = 125 °C	0.485	0.540	
		6 A		0.570	0.640	
Reverse leakage current per leg	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	-	25	μA
		T <sub>J</sub> = 125 °C		-	3	mA
Junction capacitance per leg	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		240	-	pF
Series inductance per leg	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg	В	DC operation	4.7	
Maximum thermal resistance, junction to case per device	R <sub>thJC</sub>		2.35	°C/W
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>		0.3	
Approximate weight			0.3	g
			0.01	OZ.
Madding do to		Case style I-PAK	6CL	JT04
Marking device		Case style D-PAK	6CWT	04FN

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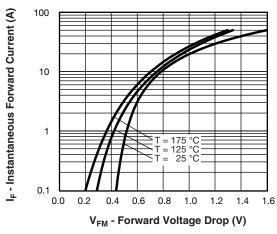


Fig. 1 - Maximum Forward Voltage Drop Characteristics

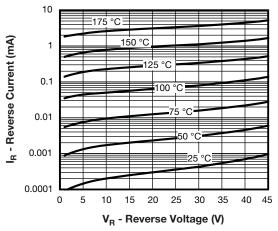


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

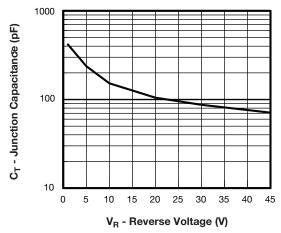


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

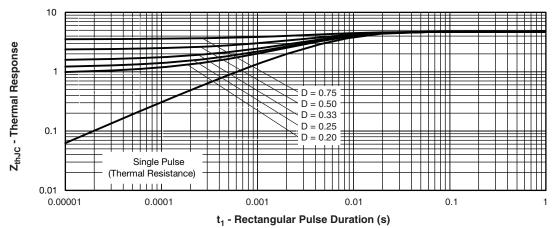


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

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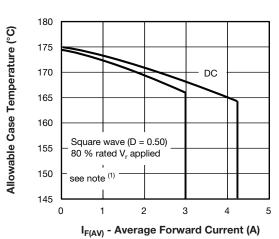


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

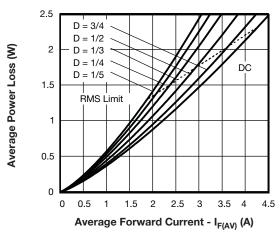
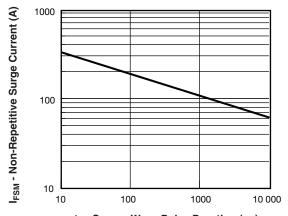


Fig. 6 - Forward Power Loss Characteristics



t<sub>p</sub> - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>th,JC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

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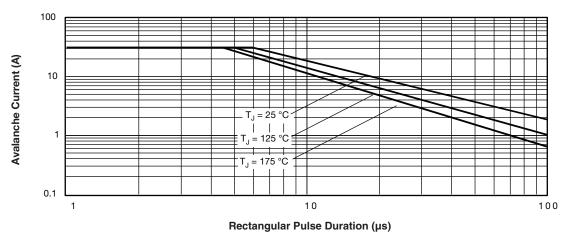


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

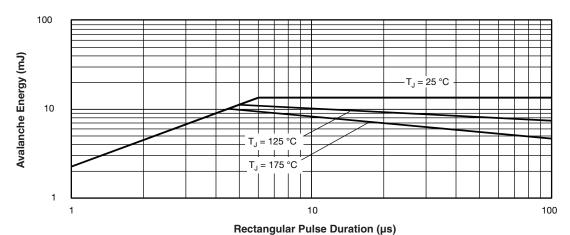
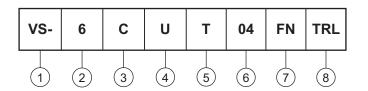


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)

### Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

Device code



1 - Vishay Semiconductors product

2 - Current rating (6 A)

Circuit configuration:

C = Common cathode

4 - Package:

• U = I-PAK

•W=D-PAK

5 - T = Trench

6 - Voltage rating (04 = 45 V)

- TO-252AA (D-PAK)

8 - D-PAK, I-PAK:

None = Tube (75 pieces)

D-PAK only:

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

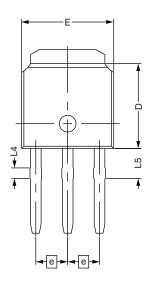
LINKS TO RELATED DOCUMENTS					
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024			
Dimensions	D-PAK (TO-252AA)	www.vishay.com/doc?95448			
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025			
	D-PAK (TO-252AA)	www.vishay.com/doc?95059			
Packaging information		www.vishay.com/doc?95033			
SPICE model		www.vishay.com/doc?95038			

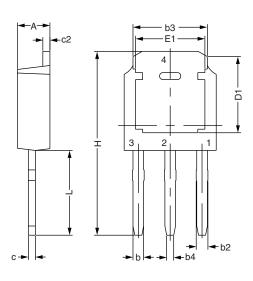


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### I-PAK - S

#### **DIMENSIONS FOR I-PAK - S** in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS				
STWIBOL	MIN.	NOM.	MAX.		
E	6.40	6.60	6.70		
L	3.98	4.13	4.28		
L4	0.66	0.76	0.86		
L5	1.96	2.16	2.36		
D	6.00	6.10	6.20		
Н	11.05	11.25	11.45		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
b4	0.41	0.51	0.61		
е	2.286 BSC				
Α	2.20	2.20 2.30			
С	0.40	0.50	0.60		
c2	0.40	0.40 0.50 0.			
D1	5.30		-		
E1	4.40		-		



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